What is claimed is:

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A method of manufacturing a semiconductor device,
comprising:

forming terminal portions convexly protruding on a surface of first conductive foil by etching the first conductive foil except portions to become terminals;

superimposing a resin sheet on the first conductive foil such that the terminal portions are embedded in the resin sheet;

constructing a laminated sheet by superimposing second conductive foil on the resin sheet;

forming a conductive pattern by etching the second conductive foil;

electrically connecting the conductive pattern and the terminal portions;

15 electrically isolating the terminal portions from each other:

firmly fixing a semiconductor element to the laminated sheet and electrically connecting the semiconductor element and the conductive pattern; and

forming sealing resin on a surface of the laminated sheet such that the semiconductor element is covered by the sealing resin.

- 2. The method according to claim 1, wherein the terminal portions are electrically isolated from each other by etching the first conductive foil from a back thereof.
- 3. The method according to claim 1, wherein the resin sheet is made of soluble resin, and side surfaces of the terminal portions are exposed by removing the resin sheet.

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- 4. The method according to claim 1, wherein the semiconductor element is connected face-up, and an electrode of the semiconductor element and the conductive pattern are connected through a fine metallic wire.
- 5. The method according to claim 1, wherein the semiconductor element is mounted face-down, and an electrode of the semiconductor element and the conductive pattern are connected through a bump electrode.